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view Online at https://defor	
Inclosure Material:	
Metal	
Overall Length:	
1.253 inches	
Function For Which Desig	yned:
Rectifier	
Mounting Facility Quantity	y:
1	
Joint Electronic Device E	ngineering Council/jedec/case Outline Designation:
Do-4	
Electrode Internally-elect	rically Connected To Case:
Cathode	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flat	S:
Between 0.424 inches and	0.437 inches
Thread Size:	
0.190 inches	
Semiconductor Material:	
Silicon	
/oltage Rating In Volts Pe	er Characteristic:
0.0 reverse voltage, insta	antaneous and 50.0 working peak reverse voltage
Current Rating Per Chara	cteristic:
100.00 amperes forward cu	irrent, average preset
Maximum Operating Tem	purature Per Measurement Point:
175.0 degrees celsius junct	ion
Test Data Document:	
31349-mil-prf-19500 specifi	cation (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
ormat; excludes commerc	ial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and perform	ance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator	:
Unf	
Terminal Type And Quant	ity:
1 tab, solder lug and 1 thre	aded stud
Specification Data:	
81349-mil-prf-19500/478 gc	overnment specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	

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Fiig: A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.